

# HT24LC02

# CMOS 2K 2-Wire Serial EEPROM

### **Features**

• Operating voltage: 2.2V~5.5V

• Low power consumption

- Operation: 5mA max.

- Standby: 5μA max.

• Internal organization: 256×8

· 2-wire serial interface

· Write cycle time: 5ms max.

• Automatic erase-before-write operation

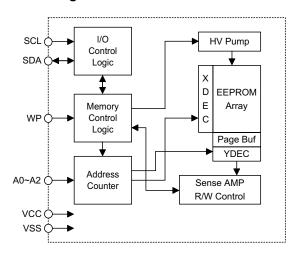
- · Partial page write allowed
- 8-byte Page write modes
- Write operation with built-in timer
- · Hardware controlled write protection
- 40-year data retention
- 10<sup>6</sup> erase/write cycles per word
- Commercial temperature range (0°C to +70°C)
- 8-pin DIP/SOP/TSSOP package

### **General Description**

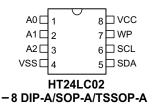
The HT24LC02 is a 2K-bit serial read/write non-volatile memory device using the CMOS floating gate process. Its 2048 bits of memory are organized into 256 words and each word is 8 bits. The device is optimized for use in many industrial and commercial applications where

low power and low voltage operation are essential. Up to eight HT24LC02 devices may be connected to the same 2-wire bus. The HT24LC02 is guaranteed for 1M erase/write cycles and 40-year data retention.

### **Block Diagram**



# **Pin Assignment**



## **Pin Description**

Pin Name	I/O	Description	
A0~A2	I	Address inputs	
SDA	I/O	Serial data inputs/output	
SCL	ı	Serial clock data input	
WP	ı	Write protect	
VSS	_	Negative power supply, ground	
VCC	_	Positive power supply	



# **Absolute Maximum Ratings**

Operating Temperature (Commercial)	0°C to 70°C
Storage Temperature	–50℃ to 125℃
Applied VCC Voltage with Respect to VSS	0.3V to 6.0\
Applied Voltage on any Pin with Respect to VSS	0.3V to V <sub>CC</sub> +0.3\

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

# **D.C. Characteristics**

Ta=0°C to 70°C

Cumbal	Parameter	Test Conditions		Min.	T	Max.	Unit
Symbol	V <sub>CC</sub> Conditions		Conditions	IVIII.	Тур.		
V <sub>CC</sub>	Operating Voltage	_	_	2.2	_	5.5	V
I <sub>CC1</sub>	Operating Current	5V	Read at 100kHz	_	_	2	mA
I <sub>CC2</sub>	Operating Current	5V	Write at 100kHz	_	_	5	mA
V <sub>IL</sub>	Input Low Voltage	_	_	-1	_	0.3V <sub>CC</sub>	V
V <sub>IH</sub>	Input High Voltage	_	_	0.7V <sub>CC</sub>	_	V <sub>CC</sub> +0.5	V
V <sub>OL</sub>	Output Low Voltage	2.4V	I <sub>OL</sub> =2.1mA	_	_	0.4	V
ILI	Input Leakage Current	5V	V <sub>IN</sub> =0 or V <sub>CC</sub>	_	_	1	μА
I <sub>LO</sub>	Output Leakage Current	5V	V <sub>OUT</sub> =0 or V <sub>CC</sub>		_	1	μА
I <sub>STB1</sub>	Standby Current	5V	V <sub>IN</sub> =0 or V <sub>CC</sub>	_	_	5	μА
I <sub>STB2</sub>	Standby Current	2.4V	V <sub>IN</sub> =0 or V <sub>CC</sub>	_	_	4	μА
C <sub>IN</sub>	Input Capacitance (See Note)	_	f=1MHz 25°C	_	_	6	pF
C <sub>OUT</sub>	Output Capacitance (See Note)	_	f=1MHz 25°C	_	_	8	pF

Note: These parameters are periodically sampled but not 100% tested

Rev. 1.10 2 November 5, 2002



# A.C. Characteristics

Ta=0°C to 70°C

Cumbal	Parameter	Remark	Standard Mode*		V <sub>CC</sub> =5V±10%		Unit
Symbol	Parameter	Remark	Min.	Max.	Min.	Max.	Unit
f <sub>SK</sub>	Clock Frequency	_	_	100	_	400	kHz
t <sub>HIGH</sub>	Clock High Time	_	4000	_	600	_	ns
t <sub>LOW</sub>	Clock Low Time	_	4700	_	1200	_	ns
t <sub>r</sub>	SDA and SCL Rise Time	Note	_	1000	_	300	ns
t <sub>f</sub>	SDA and SCL Fall Time	Note	_	300		300	ns
t <sub>HD:STA</sub>	START Condition Hold Time	After this period the first clock pulse is generated	4000	_	600	_	ns
t <sub>SU:STA</sub>	START Condition Setup Time	Only relevant for repeated START condition	4000	_	600	_	ns
t <sub>HD:DAT</sub>	Data Input Hold Time	_	0	_	0	_	ns
t <sub>SU:DAT</sub>	Data Input Setup Time	_	200	_	100	_	ns
t <sub>SU:STO</sub>	STOP Condition Setup Time	_	4000	_	600	_	ns
t <sub>AA</sub>	Output Valid from Clock	_	_	3500	_	900	ns
t <sub>BUF</sub>	Bus Free Time	Time in which the bus must be free before a new transmission can start	4700	_	1200	_	ns
t <sub>SP</sub>	Input Filter Time Constant (SDA and SCL Pins)	Noise suppression time	_	100	_	50	ns
t <sub>WR</sub>	Write Cycle Time	_	_	5	_	5	ms

Note: These parameters are periodically sampled but not 100% tested

For relative timing, refer to timing diagrams

<sup>\*</sup> The standard mode means V<sub>CC</sub>=2.2V to 5.5V



### **Functional Description**

### • Serial clock (SCL)

The SCL input is used for positive edge clock data into each EEPROM device and negative edge clock data out of each device.

#### Serial data (SDA)

The SDA pin is bidirectional for serial data transfer. The pin is open-drain driven and may be wired-OR with any number of other open-drain or open collector devices.

#### A0, A1, A2

The A2, A1 and A0 pins are device address inputs that are hard wired for the HT24LC02. As many as eight 2K devices may be addressed on a single bus system (the device addressing is discussed in detail under the Device Addressing section).

### · Write protect (WP)

The HT24LC02 has a write protect pin that provides hardware data protection. The write protect pin allows normal read/write operations when connected to the  $V_{SS}$ . When the write protect pin is connected to Vcc, the write protection feature is enabled and operates as shown in the following table.

WP Pin Status	Protect Array
At V <sub>CC</sub>	Full Array (2K)
At V <sub>SS</sub>	Normal Read/Write Operations

#### **Memory organization**

### • HT24LC02, 2K Serial EEPROM

Internally organized with 256 8-bit words, the 2K requires an 8-bit data word address for random word addressing.

### **Device operations**

#### · Clock and data transition

Data transfer may be initiated only when the bus is not busy. During data transfer, the data line must remain stable whenever the clock line is high. Changes in data line while the clock line is high will be interpreted as a START or STOP condition.

### · Start condition

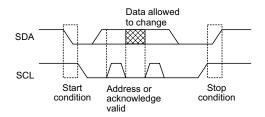
A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (refer to Start and Stop Definition Timing diagram).

#### · Stop condition

A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (refer to Start and Stop Definition Timing Diagram).

### Acknowledge

All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a zero to acknowledge that it has received each word. This happens during the ninth clock cycle.



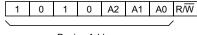
#### **Device addressing**

The 2K EEPROM devices all require an 8-bit device address word following a start condition to enable the chip for a read or write operation. The device address word consist of a mandatory one, zero sequence for the first four most significant bits (refer to the diagram showing the Device Address). This is common to all the EEPROM device.

The next three bits are the A2, A1 and A0 device address bits for the 2K EEPROM. These three bits must compare to their corresponding hard-wired input pins.

The 8th bit of device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

If the comparison of the device address succeed the EEPROM will output a zero at ACK bit. If not, the chip will return to a standby state.



Device Address

### Write operations

### · Byte write

A write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a zero and then clock in the first 8-bit data word. After receiving the 8-bit data word, the EEPROM will output a zero and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally-timed write cycle to the non-volatile memory. All inputs are disabled during this write cycle and EEPROM will not respond until the write is completed (refer to Byte write timing).



### · Page write

The 2K EEPROM is capable of an 8-byte page write. A page write is initiated the same as byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges the receipt of the first data word, the microcontroller can transmit up to seven more data words. The EEPROM will respond with a zero after each data word received. The microcontroller must terminate the page write sequence with a stop condition.

The data word address lower three (2K) bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location (refer to Page write timing).

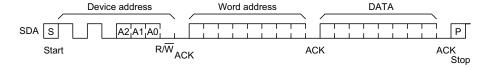
### · Acknowledge polling

Since the device will not acknowledge during a write cycle, this can be used to determine when the cycle is complete (this feature can be used to maximize bus throughput). Once the stop condition for a write command has been issued from the master, the device initiates the internally timed write cycle. ACK polling can be initiated immediately. This involves the master sending a start condition followed by the control byte for a write command (R/W=0). If the device is still busy with the write cycle, then no ACK will be returned. If the cycle is completed, then the device will return the ACK and the master can then proceed with the next read or write command.

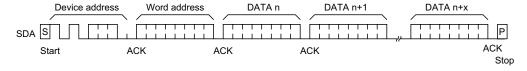
#### · Write protect

The HT24LC02 can be used as a serial ROM when the WP pin is connected to VCC. Programming will be inhibited and the entire memory will be write-protected.

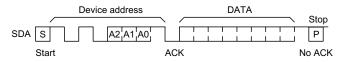
### Byte write timing

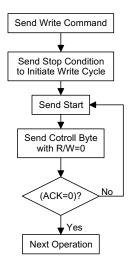


# Page write timing



## Current read timing





Acknowledge polling flow

#### · Read operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to one. There are three read operations: current address read, random address read and sequential read.

#### · Current address read

The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address roll over during read from the last byte of the last memory page to the first byte of the first page. The address roll over during write from the last byte of the current page to the first byte of the same page. Once the device address with the read/write select bit set to one is clocked in and acknowledged by the EEPROM, the current address data word is seri-



ally clocked out. The microcontroller does not respond with an input zero but generates a following stop condition (refer to Current read timing).

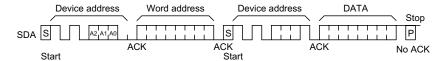
#### · Random read

A random read requires a dummy byte write sequence to load in the data word address which is then clocked in and acknowledged by the EEPROM. The microcontroller must then generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a zero but does generates a following stop condition (refer to Random read timing).

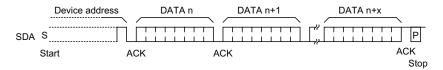
### · Sequential read

Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledgment. As long as the EEPROM receives an acknowledgment, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will roll over and the sequential read continues. The sequential read operation is terminated when the microcontroller does not respond with a zero but generates a following stop condition.

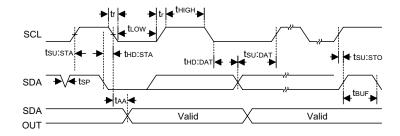
### Random read timing

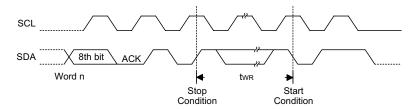


### Sequential read timing



### **Timing Diagrams**





Note: The write cycle time t<sub>WR</sub> is the time from a valid stop condition of a write sequence to the end of the valid start condition of sequential command.



# **Package Information**

# 8-pin DIP (300mil) outline dimensions



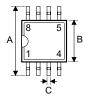




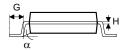
Complete		Dimensions in mil			
Symbol	Min.	Nom.	Max.		
Α	355	_	375		
В	240	_	260		
С	125	_	135		
D	125	_	145		
E	16	_	20		
F	50	_	70		
G	_	100	_		
Н	295	_	315		
1	335	_	375		
α	0°	_	15°		



# 8-pin SOP (150mil) outline dimensions



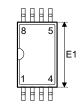


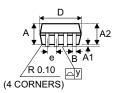


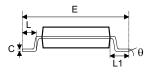
Cumbal	Dimensions in mil			
Symbol	Min.	Nom.	Max.	
А	228	_	244	
В	149	_	157	
С	14	_	20	
C'	189	_	197	
D	53	_	69	
E	_	50	_	
F	4	_	10	
G	22	_	28	
Н	4	_	12	
α	0°	_	10°	



# 8-pin TSSOP outline dimensions





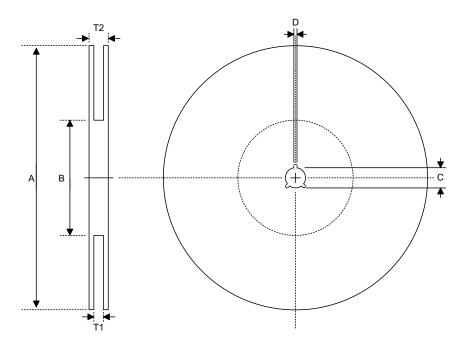


Cumhal	Dimensions in mm		
Symbol	Min.	Nom.	Max.
А	1.05	_	1.20
A1	0.05	_	0.15
A2	0.95	_	1.05
В	_	0.25	_
С	0.11	_	0.15
D	2.90	_	3.10
Е	6.20	_	6.60
E1	4.30	_	4.50
е	_	0.65	_
L	0.50	_	0.70
L1	0.90	_	1.10
у	_	_	0.10
θ	0°	_	8°



# **Product Tape and Reel Specifications**

# Reel dimensions



# SOP 8N

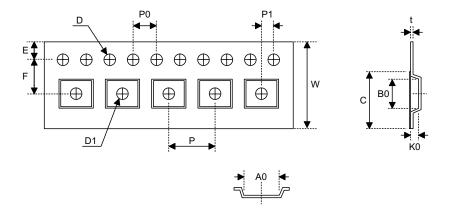
Symbol	Description	Dimensions in mm
Α	Reel Outer Diameter	330±1.0
В	Reel Inner Diameter	62±1.5
С	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.15
T1	Space Between Flange	12.8+0.3 -0.2
T2	Reel Thickness	18.2±0.2

# TSSOP 8L

Symbol	Description	Dimensions in mm
Α	Reel Outer Diameter	330±1.0
В	Reel Inner Diameter	62±1.5
С	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.5
T1	Space Between Flange	12.8+0.3 -0.2
T2	Reel Thickness	18.2±0.2



# Carrier tape dimensions



# SOP 8N

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0+0.3 -0.1
Р	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	5.5±0.1
D	Perforation Diameter	1.55±0.1
D1	Cavity Hole Diameter	1.5+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	6.4±0.1
В0	Cavity Width	5.20±0.1
K0	Cavity Depth	2.1±0.1
t	Carrier Tape Thickness	0.3±0.05
С	Cover Tape Width	9.3

## TSSOP 8L

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0+0.3 _0.1
Р	Cavity Pitch	8.0±0.1
Е	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	5.5±0.5
D	Perforation Diameter	1.5+0.1
D1	Cavity Hole Diameter	1.5+0.1
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	7.0±0.1
В0	Cavity Width	3.6±0.1
K0	Cavity Depth	1.6±0.1
t	Carrier Tape Thickness	0.3±0.013
С	Cover Tape Width	9.3



### Holtek Semiconductor Inc. (Headquarters)

No.3, Creation Rd. II, Science Park, Hsinchu, Taiwan

Tel: 886-3-563-1999 Fax: 886-3-563-1189 http://www.holtek.com.tw

### Holtek Semiconductor Inc. (Sales Office)

4F-2, No. 3-2, YuanQu St., Nankang Software Park, Taipei 115, Taiwan Tel: 886-2-2655-7070

Tel: 886-2-2655-7070 Fax: 886-2-2655-7373

Fax: 886-2-2655-7383 (International sales hotline)

# Holtek Semiconductor (Shanghai) Inc.

7th Floor, Building 2, No.889, Yi Shan Rd., Shanghai, China

Tel: 021-6485-5560 Fax: 021-6485-0313 http://www.holtek.com.cn

### Holtek Semiconductor (Hong Kong) Ltd.

Block A, 3/F, Tin On Industrial Building, 777-779 Cheung Sha Wan Rd., Kowloon, Hong Kong Tel: 852-2-745-8288

Tel: 852-2-745-8288 Fax: 852-2-742-8657

### Holmate Semiconductor, Inc.

46712 Fremont Blvd., Fremont, CA 94538

Tel: 510-252-9880 Fax: 510-252-9885 http://www.holmate.com

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Rev. 1.10 12 November 5, 2002